**Product data sheet** 

# 1. General description

Ultrafast power diode in a SMC package.

### 2. Features and benefits

- Fast switching
- SMC package
- High voltage capability
- · Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- Soft recovery characteristic

# 3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- · use in switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute	maximum rating			
$V_{RRM}$	repetitive peak reverse voltage		600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; $T_{lead} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3	8	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>lead</sub> ≤ 95 °C; square-wave pulse	16	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	200	Α

**MUR860** 

Ultrafast power diode

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 A
2	A	anode	1 2	K — A 001aaa020

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MUR860	SMC	MUR860J	Reel	3000	SMCS	16-Aug-2017

# 7. Marking

#### Table 4. Marking codes

Type number	Marking codes
MUR860	860

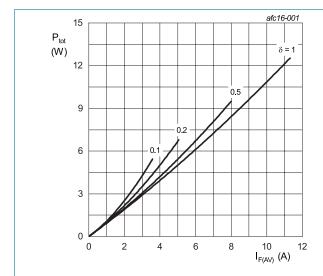
Ultrafast power diode

# 8. Limiting values

#### **Table 5. Limiting values**

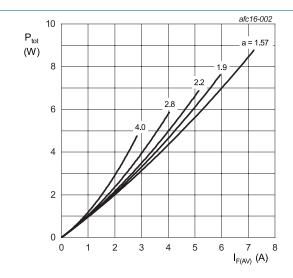
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		600	V
$V_{\text{RWM}}$	crest working reverse voltage		600	V
$V_R$	reverse voltage	DC	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; $T_{lead} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3	8	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>lead</sub> ≤ 95 °C; square-wave pulse	16	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	200	Α
T <sub>stg</sub>	storage temperature		-65 to 175	°C
T <sub>j</sub>	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.918 \text{ V; } R_s = 0.0168 \text{ } \Omega \end{split}$$

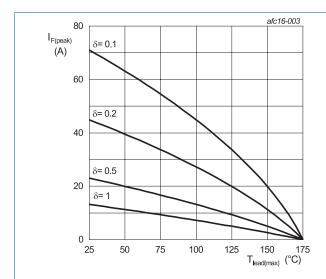
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor =  $I_{F(RMS)}/I_{F(AV)}$  $V_o$  = 0.918 V;  $R_s$  = 0.0168  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

Ultrafast power diode





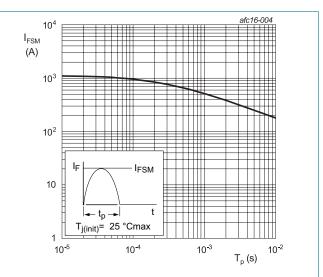


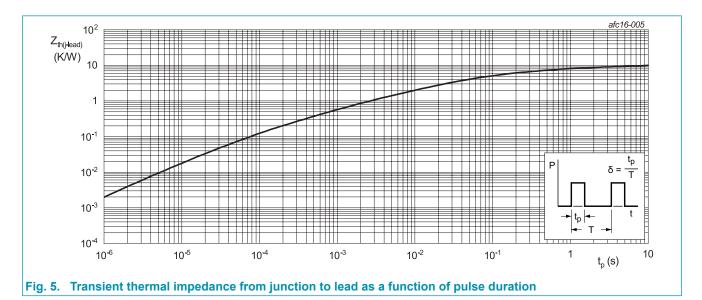
Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

Ultrafast power diode

## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

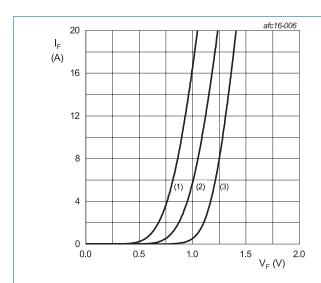
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 5</u>	-	-	10	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	75	-	K/W



# 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics		'	'		
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	-	1.25	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	-	1.05	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	400	μA
Dynamic	characteristics		'			
Q <sub>r</sub> I	reverse charge	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	494	-	nC
		I <sub>F</sub> = 8 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us; T <sub>j</sub> = 125 °C; <u>Fig. 7</u>	-	983	-	nC
t <sub>rr</sub> r	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	66	90	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	93	-	ns
		I <sub>F</sub> = 8 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us; T <sub>j</sub> = 125 °C; <u>Fig. 7</u>	-	130	-	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	11	-	А
		I <sub>F</sub> = 8 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us; T <sub>i</sub> = 125 °C; <u>Fig. 7</u>	-	15	-	А



 $V_o$  = 0.918 V;  $R_s$  = 0.0168  $\Omega$ 

(1)  $T_j = 150 \,^{\circ}\text{C}$ ; typical values (2)  $T_j = 150 \,^{\circ}\text{C}$ ; maximum values (3)  $T_j = 25 \,^{\circ}\text{C}$ ; maximum values

Fig. 6. Forward current as a function of forward voltage

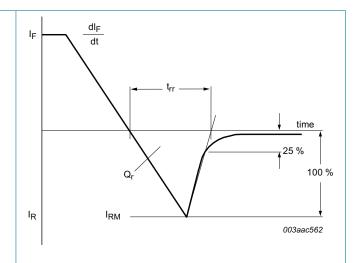
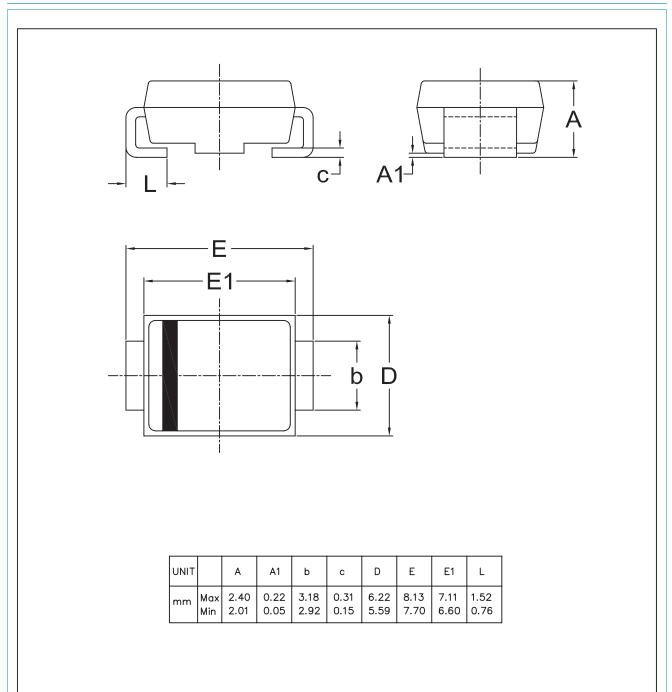


Fig. 7. Reverse recovery definitions; ramp recovery

# 11. Package outline



Remark: Dimensions D and E1 do not include mold flash.

#### Ultrafast power diode

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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For more information, please visit: http://www.ween-semi.com
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